

# TO-126 Plastic-Encapsulate Transistors

## MJE13003 TRANSISTOR (NPN)

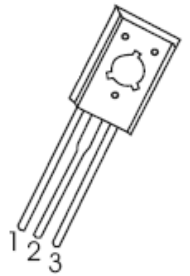
### FEATURES

- Power Switching Applications

### MAXIMUM RATINGS ( $T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	600	V
$V_{CEO}$	Collector-Emitter Voltage	400	V
$V_{EBO}$	Emitter-Base Voltage	6	V
$I_C$	Collector Current -Continuous	1	A
$P_C$	Collector Power Dissipation	1.25	W
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	100	$^{\circ}\text{C}/\text{W}$
$T_J$	Junction Temperature	150	$^{\circ}\text{C}$
$T_{stg}$	Storage Temperature	-55~+150	$^{\circ}\text{C}$

TO-126



1. BASE
2. COLLECTOR
3. EMITTER

### ELECTRICAL CHARACTERISTICS ( $T_a=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=0.1\text{mA}, I_E=0$	600			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}, I_B=0$	400			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=0.1\text{mA}, I_C=0$	6			V
Collector cut-off current	$I_{CBO}$	$V_{CB}=600\text{V}, I_E=0$			100	$\mu\text{A}$
Collector cut-off current	$I_{CEO}$	$V_{CE}=400\text{V}, I_B=0$			100	$\mu\text{A}$
Emitter cut-off current	$I_{EBO}$	$V_{EB}=7\text{V}, I_C=0$			10	$\mu\text{A}$
DC current gain	$h_{FE(1)*}$	$V_{CE}=10\text{V}, I_C=200\text{mA}$	9		40	
	$h_{FE(2)}$	$V_{CE}=10\text{V}, I_C=250\mu\text{A}$	5			
Collector-emitter saturation voltage	$V_{CE(sat)1}$	$I_C=200\text{mA}, I_B=40\text{mA}$			0.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=200\text{mA}, I_B=40\text{mA}$			1.1	V
Transition frequency	$f_T$	$V_{CE}=10\text{V}, I_C=100\text{mA}, f=1\text{MHz}$	5			MHz
Fall time	$t_f$	$I_C=100\text{mA}$			0.5	$\mu\text{s}$
Storage time	$t_s^*$	$I_C=100\text{mA}$	2		4	

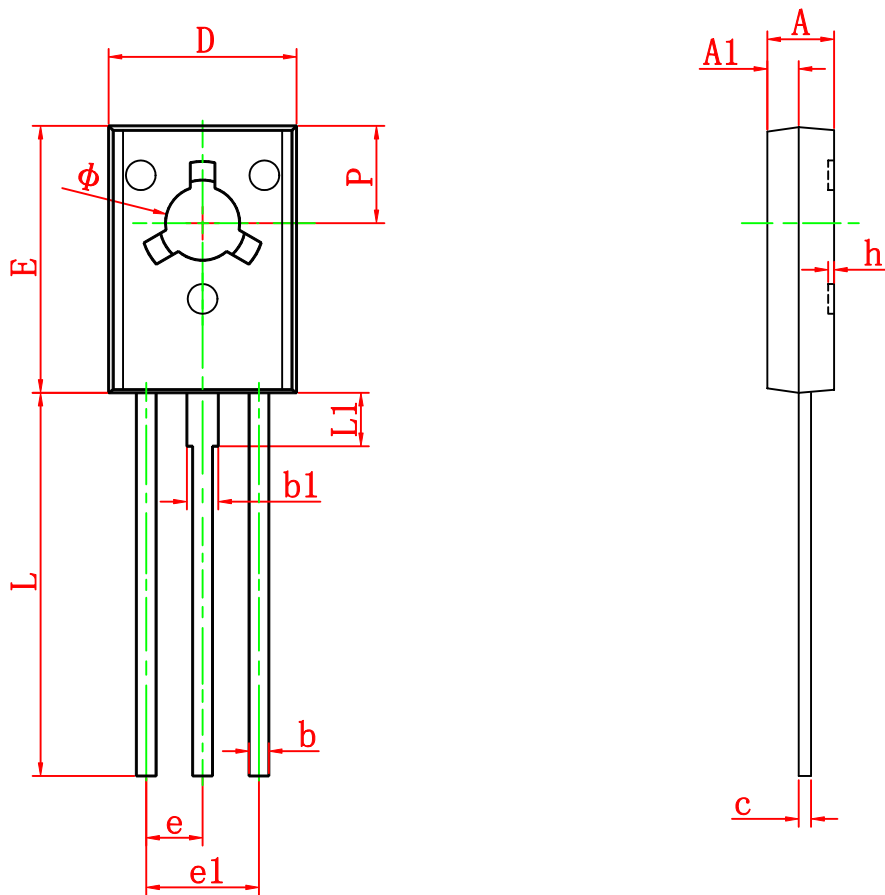
### CLASSIFICATION of $h_{FE(1)}$

Range	9-15	15-20	20-25	25-30	30-35	35-40
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### CLASSIFICATION of $t_s$

Rank	A1	A2	B1	B2
Range	2-2.5	2.5-3	3-3.5	3.5-4

# TO-126 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	2.500	2.900	0.098	0.114
A1	1.100	1.500	0.043	0.059
b	0.660	0.860	0.026	0.034
b1	1.170	1.370	0.046	0.054
c	0.450	0.600	0.018	0.024
D	7.400	7.800	0.291	0.307
E	10.600	11.000	0.417	0.433
e	2.290 TYP		0.090 TYP	
e1	4.480	4.680	0.176	0.184
h	0.000	0.300	0.000	0.012
L	15.300	15.700	0.602	0.618
L1	2.100	2.300	0.083	0.091
P	3.900	4.100	0.154	0.161
$\phi$	3.000	3.200	0.118	0.126

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